

FEATURE

- Low gate charge
- Low C_{iss}
- Fast switching
- 100% avalanche tested
- Improved dv/dt capability

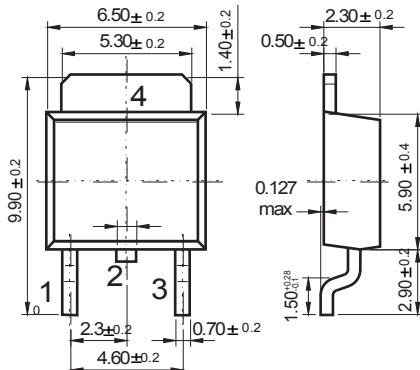
Maximum output current
 I_{OM} : 0.5 A

Output voltage
 V_o : 15V

Continuous total dissipation
 P_D : 1.25 W ($T_a = 25^\circ C$)

TO-252

Unit: mm



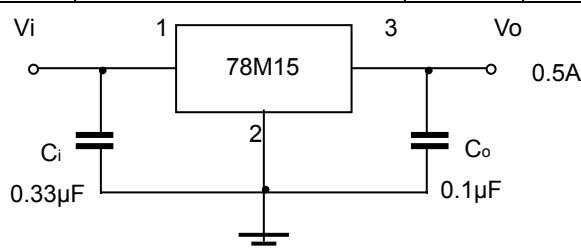
Dimensions in inches and (millimeters)

ABSOLUTE MAXIMUM RATINGS (Operating temperature range applies unless otherwise specified)

Parameter	Symbol	Value	Unit
Input Voltage	V_i	35	V
Operating Junction Temperature Range	T_{OPR}	0-+125	°C
Storage Temperature Range	T_{STG}	-65-+150	°C

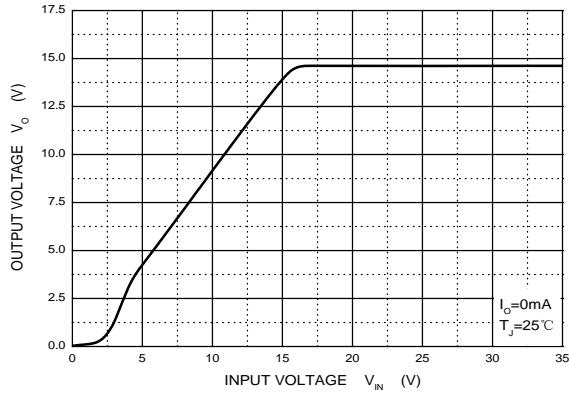
ELECTRICAL CHARACTERISTICS (Vi=23V, Io=350mA, Ci=0.33μF, Co=0.1μF, unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Output Voltage	Vo	Vi=23V, Io=350mA	25°C	14.4	15	15.6 V
		17.5≤Vi≤30V, Io=5mA~350mA Po≤15W	0-125°C	14.25	15	15.75 V
Load Regulation	ΔVo	Io=5mA~500mA	25°C		300	mV
		Io=5mA~200mA	25°C		150	mV
Line Regulation	ΔVo	17.5V≤Vi≤30V, Io=200mA	25°C		100	mV
		20V≤Vi≤26V, Io=200mA	25°C		50	mV
Quiescent Current	Iq	Vi=23V, Io=350mA	25°C		6	mA
Quiescent Current Change	ΔIq	17.5V≤Vi≤30V, Io=200mA	0-125°C		0.8	mA
	ΔIq	Vi=23V, Io=5mA~350mA	0-125°C		0.5	mA
Output Noise Voltage	V _N	10Hz≤f≤100kHz	25°C	90		μV
Ripple Rejection	RR	18.5≤Vi≤28.5V, f=120Hz, Io=300mA	0-125°C	54		dB
Dropout Voltage	Vd		25°C		2	V

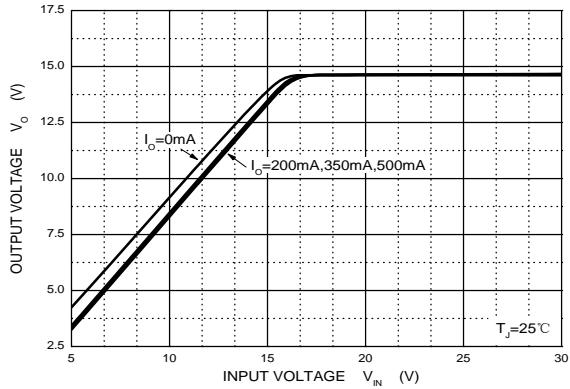
TYPICAL APPLICATION


RATING AND CHARACTERISTIC CURVES (78M15)

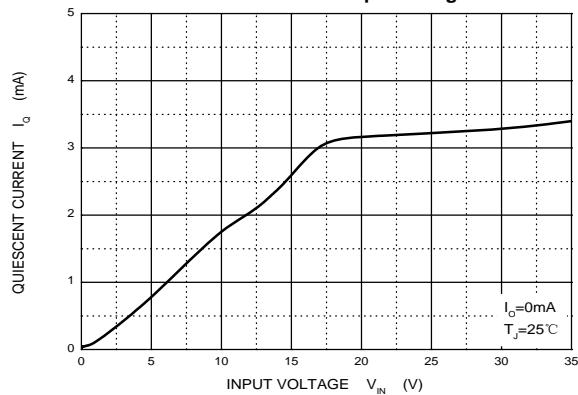
Output Characteristics



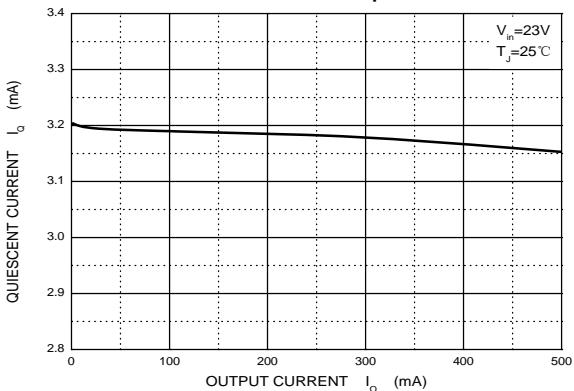
Dropout Characteristics



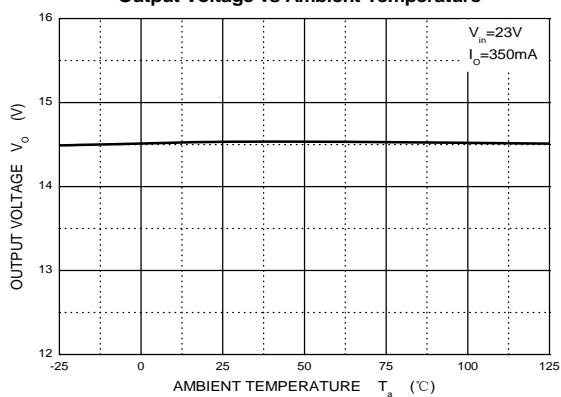
Quiescent Current vs Input Voltage



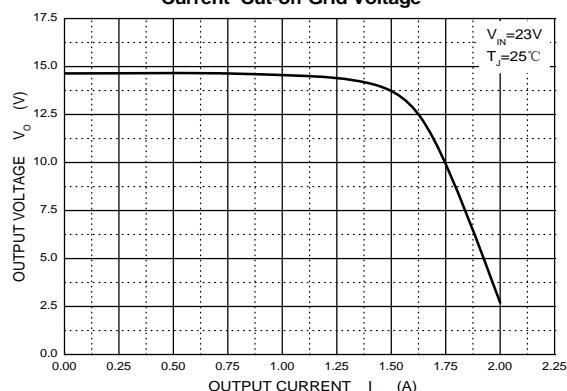
Quiescent Current vs Output Current



Output Voltage vs Ambient Temperature



Current Cut-off Grid Voltage



Power Derating Curve

